



6. Phonons

6.1 Specific heat — Debye model:

- assumptions:
- ▶ solids are elastic, isotropic homogenous continua
 - ▶ excitations: **sound waves** with **linear dispersion**
 - ▶ Bose-Einstein distribution

internal energy:

$$U(T) = \int_0^{\hbar\omega_D} \hbar\omega \mathcal{D}(\omega) f(\omega, T) d\omega$$

cut-off frequency $\rightarrow$ Debye frequency

$\propto \omega^2$

specific heat:

$$C_V = \frac{\partial U}{\partial T} = 9Nk_B \left(\frac{T}{\Theta}\right)^3 \int_0^{x_D} \frac{x^4 e^x}{(e^x - 1)^2} dx$$

$x_D = \hbar\omega_D / k_B T$

$x = \hbar\omega / k_B T$

$\Theta = \hbar\omega_D / k_B$



Limiting cases:

(i) $T \rightarrow \infty \longrightarrow x \rightarrow 0$

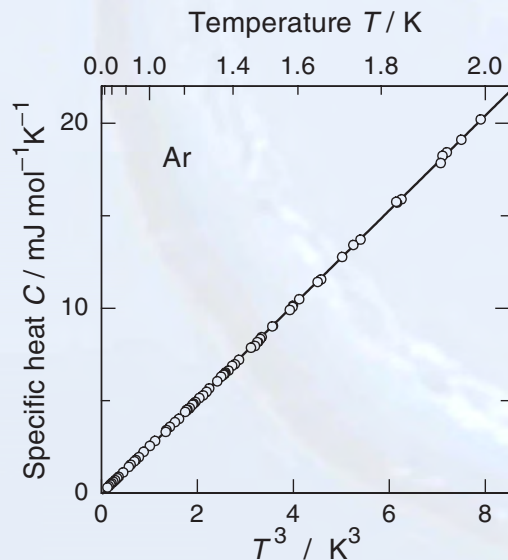
$$\lim_{x \rightarrow 0} \int_0^{x_D} \frac{x^4 e^x}{(e^x - 1)^2} dx \approx \int_0^{x_D} \frac{x^4 \cdot 1}{(1 + x - 1)^2} dx = \frac{x_D^3}{3} = \frac{1}{3} \left(\frac{\Theta}{T} \right)^3$$

$\longrightarrow C_V = 3Nk_B$ Dulong-Petit law

(ii) $T \rightarrow 0 \longrightarrow x_D \rightarrow \infty$

$$C_V = 9Nk_B \left(\frac{T}{\Theta} \right)^3 \underbrace{\int_0^{\infty} \frac{x^4 e^x}{(e^x - 1)^2} dx}_{4\pi^4/15} = \frac{12\pi^4}{5} Nk_B \left(\frac{T}{\Theta} \right)^3$$

$\longrightarrow C_V = \frac{12\pi^4}{5} Nk_B \left(\frac{T}{\Theta} \right)^3$



- ▶ perfect agreement with theory
- ▶ only small temperature range
- ▶ Debye temperature $\Theta = 92 \text{ K}$



6.1 Specific Heat



Element	Θ (K)	Element	Θ (K)	Element	Θ (K)	Element	Θ (K)
Ar	92	Cu	347	Mn	409	Sc	346
Ac*	100	Er	118	Mo	423	Se	152
Ag	227	Fe	477	N*	70	Si	645
Al	433	Ga	325	Na	156	Sm	169
Am	121	Gd	182	Nb	276	Sn	199
As	282	Ge	373	Nd	163	Sr	147
Au	162	H (para)	122	Ne	75	Ta	245
B	1480	H (orth)	114	Ni	477	Tb	176
Ba	111	³ He	19–33	Np	259	Te	152
Be	1481	Hf	252	O*	90	Th	160
Bi	120	Hg	72	Os	467	Ti	420
C (Dia.)	2250	Ho	190	Pa	185	Tl	78
C (Gra.)	413	I	109	Pb	105	Tm	200
Ca	229	In	112	Pd	271	U	248
Cd	210	Ir	420	Pr	152	V	399
Ce	179	K	91	Pt	237	W	383
Cl*	115	Kr	72	Rb	56	Xe	64
Cm	123	La	145	Re	416	Y	248
Co	460	Li	344	Rh	512	Yb	118
Cr	606	Lu	183	Ru	555	Zn	329
Cs	40	Mg	403	Sb	220	Zr	290



Compound	Θ (K)	Compound	Θ (K)	Compound	Θ (K)
AgBr*	140	Cr ₂ Cl ₃ *	360	MgO*	800
AgCl*	180	FeS ₂ *	630	MoS ₂ *	290
As ₂ O ₃ *	140	KBr	173	RbBr	131
As ₂ O ₅ *	240	KCl	235	RbCl	165
AuCu ₃	285	KI	131	RbI	103
BN*	600	InSb	206	SiO ₂ (Quartz)	470
CaF ₂	508	LiF	736	TiO ₂ * (Rutile)	450
CrCl ₂ *	80	LiCl	422	ZnS	315

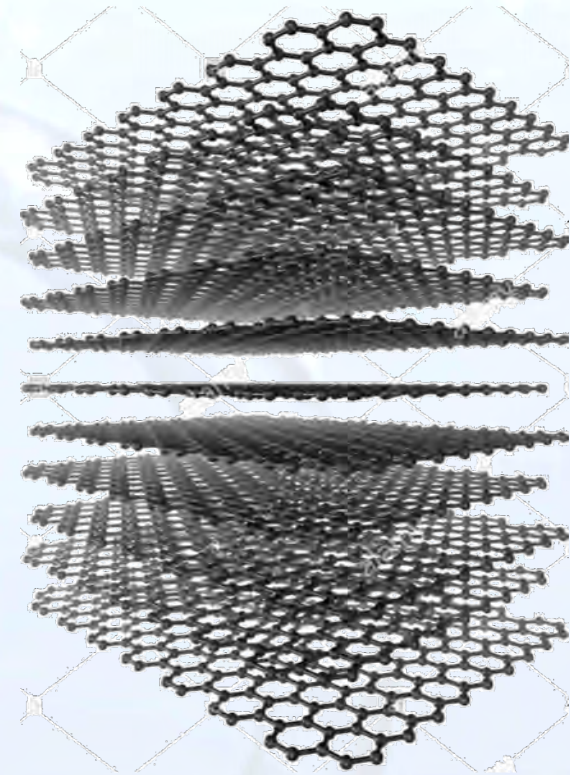
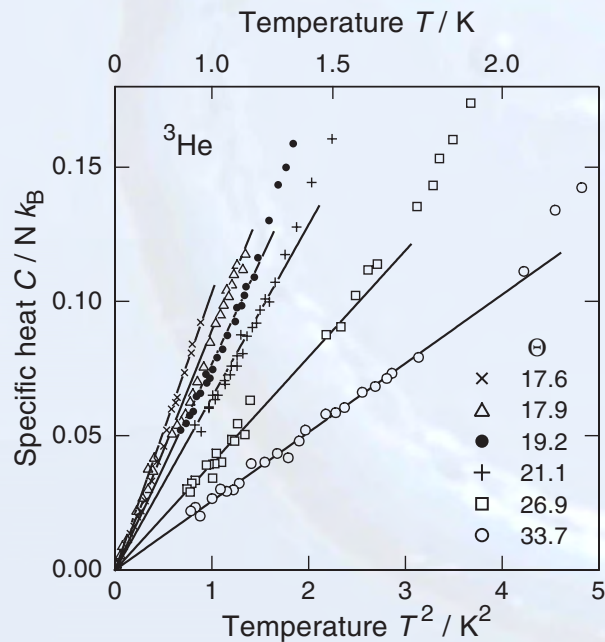


low-dimensional systems

$$D(\omega) \propto \omega^{d-1} \longrightarrow C_V \propto T^d$$

$$d = 2 \longrightarrow C_V \propto T^2$$

example: ^3He atoms on **graphite** (sub-mono layers)



- ▶ high temperatures and **low densities** $\longrightarrow$ gas: $C_V \approx N k_B$
- ▶ for $n > 0.078 \text{ \AA}^{-2}$ $\longrightarrow$ two-dimensional **solid** crystals
- ▶ increasing density $\longrightarrow \Theta$ increases
- ▶ density $0.078 \dots 0.092 \text{ per \AA}^2$ $\longrightarrow \Theta = 17.6 \dots 37.7 \text{ K}$
- ▶ at high temperatures **melting** of 2d-crystals



6.2 Heat transport

Fourier equation $\mathbf{j} = -\Lambda \nabla T$

$$\Lambda = \frac{1}{3} C v \ell$$

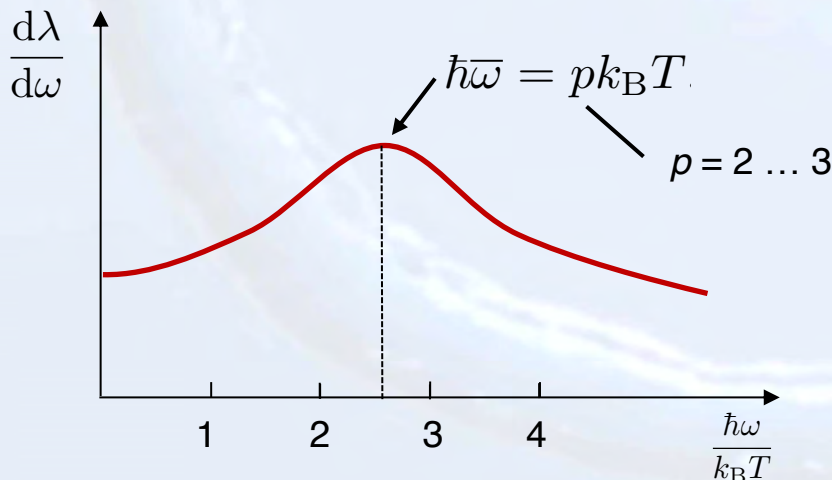
in general

$$\Lambda = \frac{1}{3} \sum_i \int c_i(\omega) v_i(\omega) \ell_i(\omega) d\omega$$

different “particles” $\longrightarrow$ phonon branches

spectral specific heat

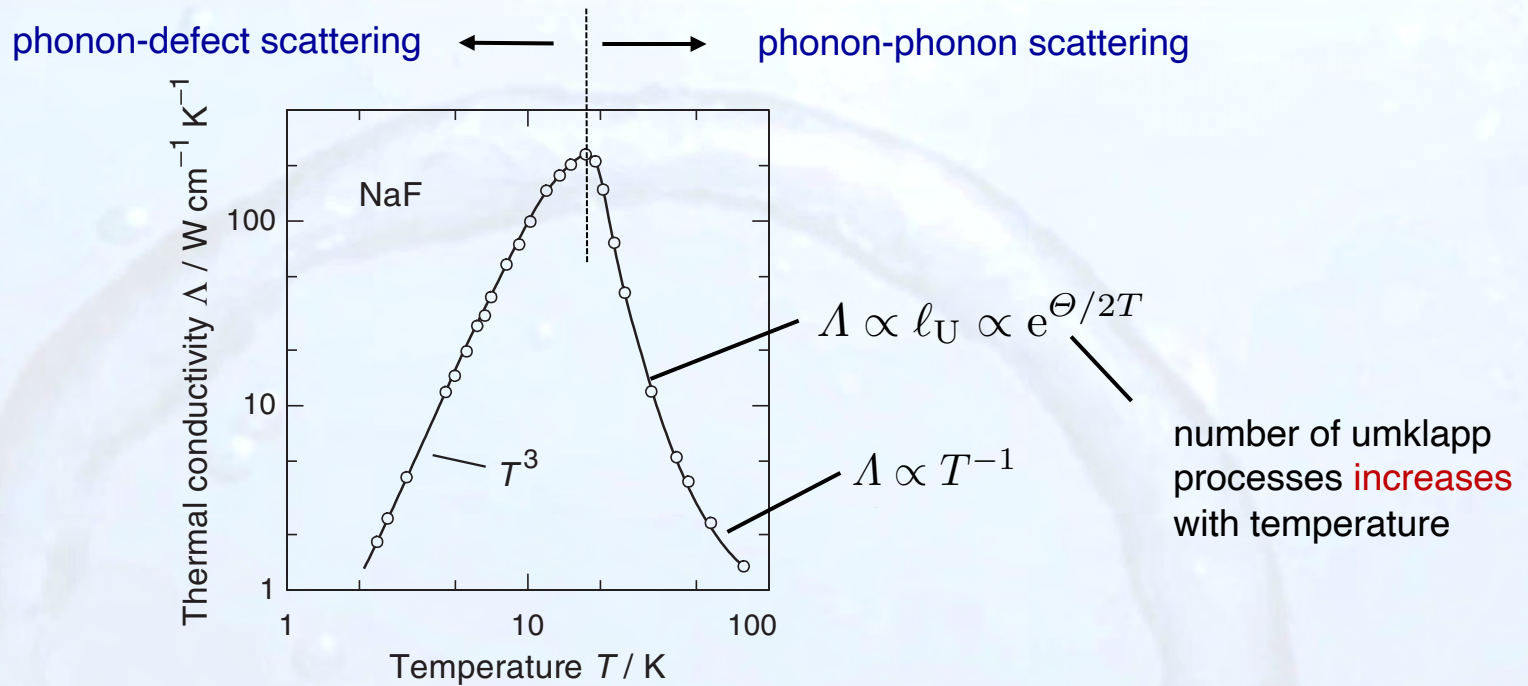
dominate phonon approximation (Debye)



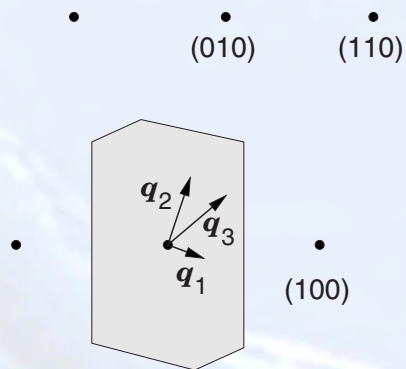
- ▶ summation and integration can be avoided
- ▶ in addition: linear dispersion



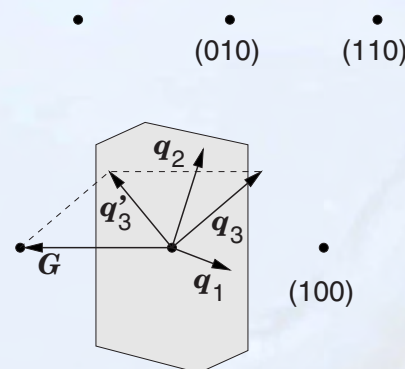
6.2 Heat Transport



normal process



umklapp process

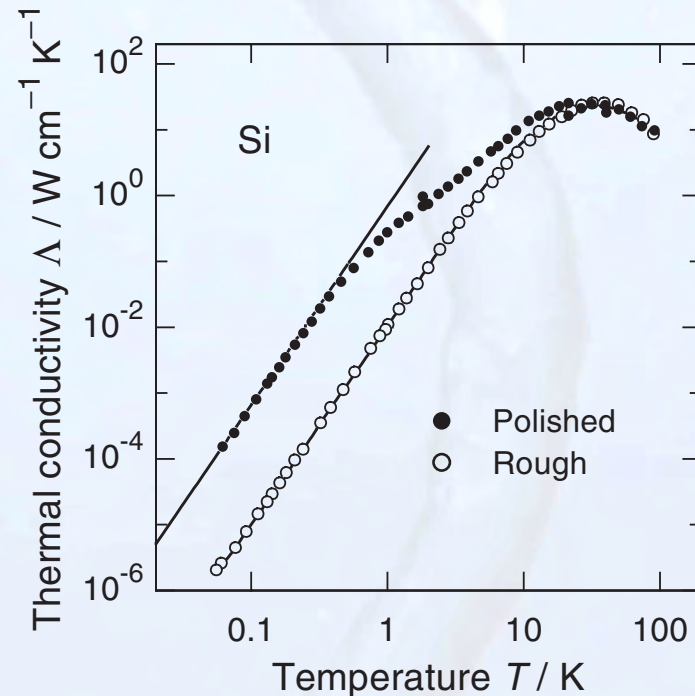
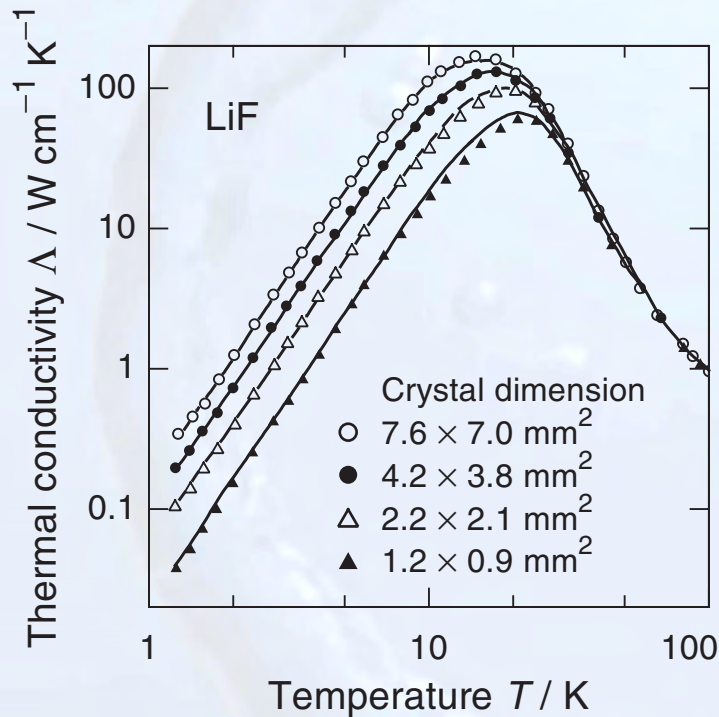




phonon-defect scattering

a) surfaces

$$\Lambda = \frac{1}{3} C v \ell \quad \xrightarrow{\ell \approx d} \quad \Lambda \approx \frac{1}{3} C_V v d \propto T^3 \quad \text{Casimir regime}$$



- ▶ depends on sample cross-section
- ▶ temperature dependence as expected

- ▶ roughed: mean free path factor 50 shorter
- ▶ polished: mean free path 7 cm, sample length

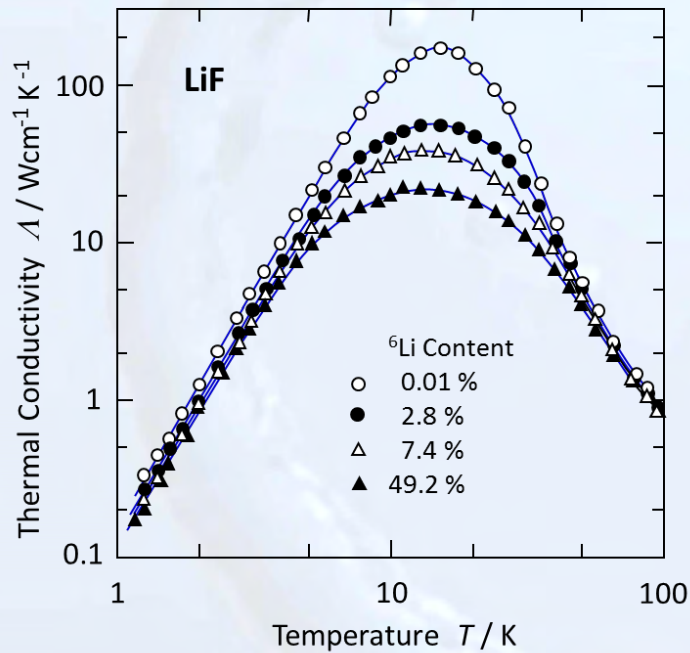


b) influence of point defects (elastic scattering)

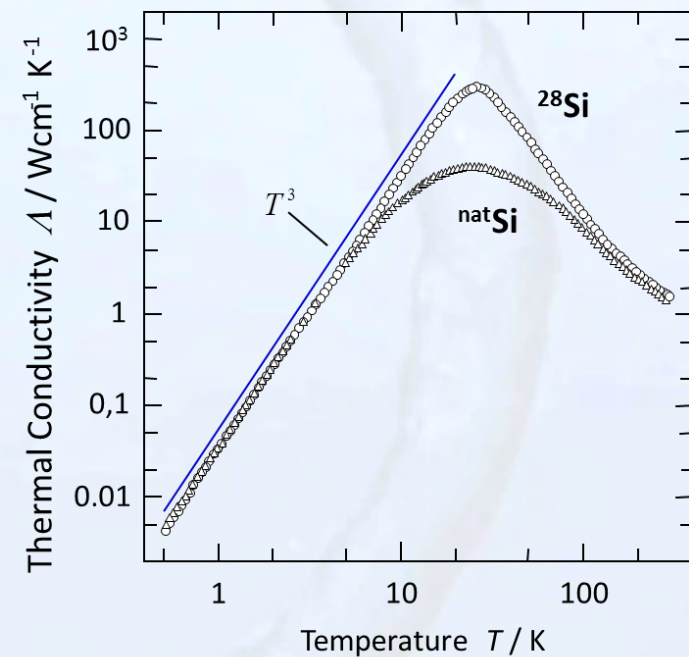
→ Rayleigh scattering, since $\lambda_{\text{phonon}} \gg d_{\text{defect}}$

$$\ell^{-1} = \frac{n_p V_A^2}{4\pi} \left(\frac{\Delta M}{M} \right)^2 q^4 \propto \omega^4$$

is important at intermediate temperatures, since at low temperature q is too small and at high temperatures phonon-phonon scattering dominates



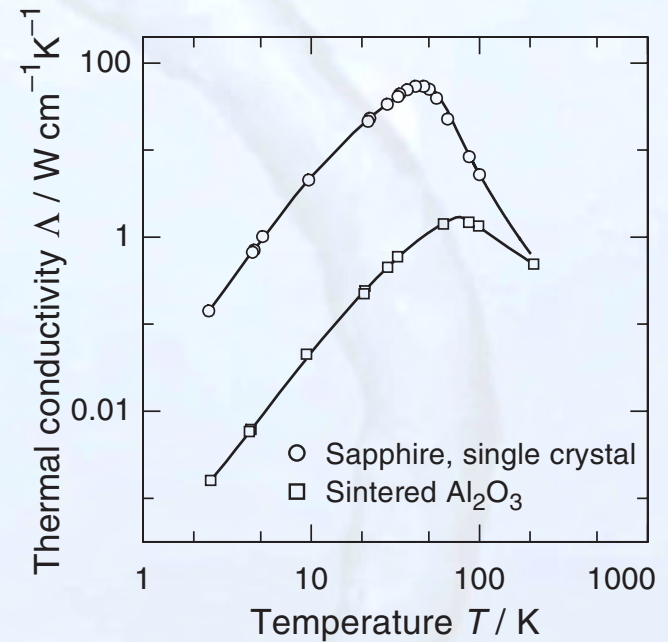
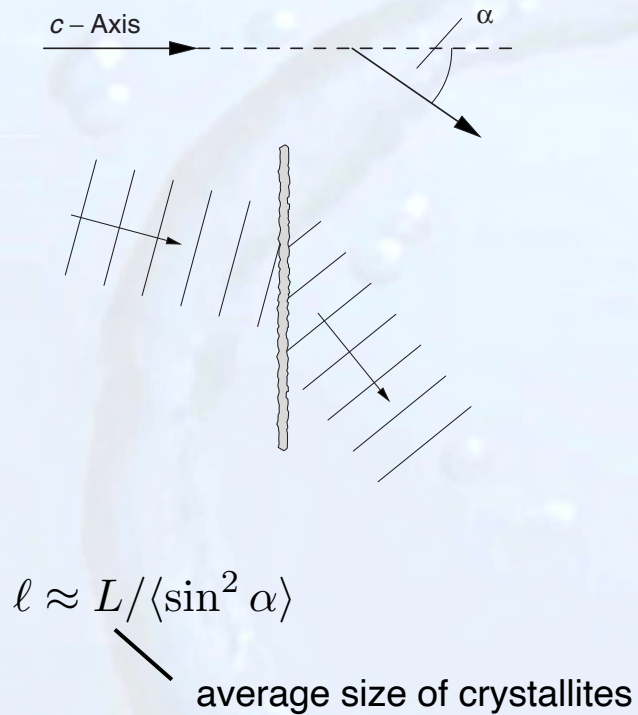
- ▶ adding ^6Li **reduces** heat transport
- ▶ **maximum** becomes **rounded**



- ▶ ^{28}Si : 10% of all Si atoms have mass difference
- ▶ ^{28}Si : sharp peak → little scattering on point defects



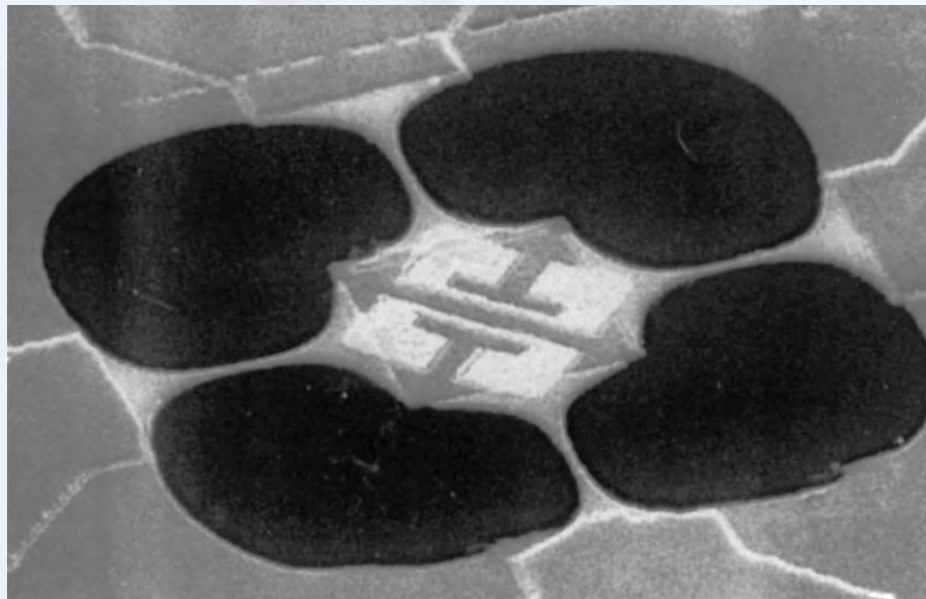
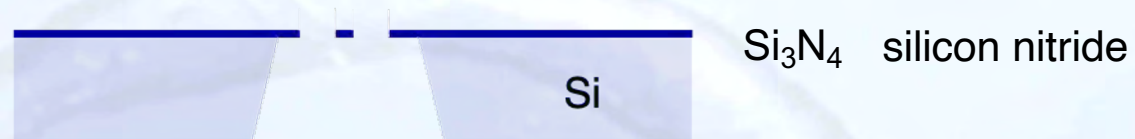
c) grain boundaries



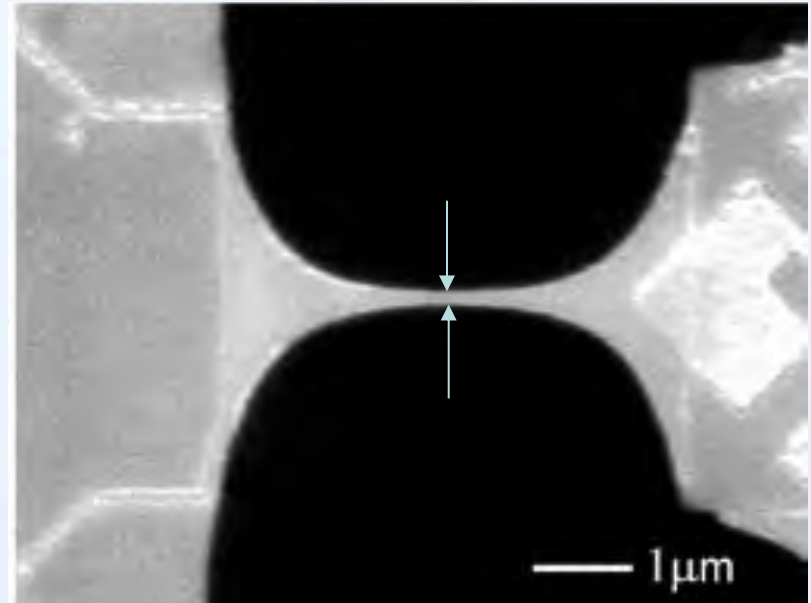
- ▶ sapphire single crystal: 1.5 mm
- ▶ sintered Al_2O_3 powder 5 ... 30 μm



Geometry of setup:



$4 \times 4 \mu\text{m}^3$ island with gold resistors as heaters and thermometers



minimal width of bridge $w < 200 \text{ nm}$



heat flow:

$$J = \frac{1}{L} \sum_q \hbar \omega_q v_q$$

length of sample all thermally excited phonons

summation $\longrightarrow$ integration

$$J = \sum_i \frac{1}{L} \int_0^\infty \mathcal{D}_i^1(q) \hbar \omega_i v_i [f_h(\omega, T) - f_c(\omega, T)] dq$$

phonons modes group velocity

assumptions

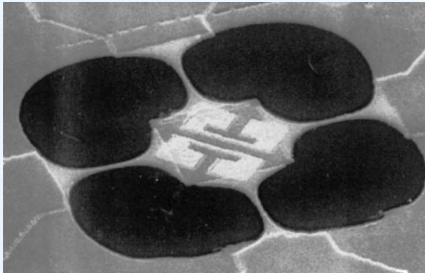
► **transmission coefficient** for coupling between bath and thin bar = 1► $\mathcal{D}_i^1(q) = L/2\pi$, $q \longleftrightarrow \omega$, $\frac{\partial q}{\partial \omega}$ cancels with $v = \frac{\partial \omega}{\partial q}$ ► small temperature difference ΔT $\longrightarrow [f_h(\omega, T) - f_c(\omega, T)]$ can be **expanded**, keep only **terms linear** in ΔT

$$\hookrightarrow G = \frac{J}{\Delta T} = \frac{k_B^2 T}{h} \sum_i \int_0^\infty \frac{x^2 e^x}{(e^x - 1)^2} dx = N_i \underbrace{\frac{\pi^2}{3} \frac{k_B^2 T}{h}}_{\text{quantum of thermal conductance } G_0} = N_i G_0 \quad \hookrightarrow \boxed{G = N_i G_0}$$

number of contributing modes



for given geometry



$$N_i = 4 \times 4 \text{ legs} = 16$$

modes:

- 1 longitudinal (dilatation)
- 1 torsional
- 2 bending

$$G_0 = (9.456 \times 10^{-13} \text{ W K}^{-2}) T$$

► transition roughly at 0.8 K

$$T_{\text{crossover}} \approx \frac{h\nu}{2wk_B} \approx 0.8 \text{ K}$$

expected for: $q_{\text{th}} \approx k_B T / (\hbar \nu) < \Delta q = \frac{\pi}{w}$

spacing between lowest lying modes

